

DESCRIPTION

The AP62201 is a 2A, synchronous buck converter with a wide input voltage range of 4.2V to 18V. The device fully integrates a $90m\Omega$ high-side power MOSFET and a $65m\Omega$ low-side power MOSFET to provide high-efficiency step-down DC-DC conversion.

The AP62201 device is easily used by minimizing the external component count due to its adoption of Constant On-Time (COT) control to achieve fast transient response, easy loop stabilization, and low output voltage ripple.

The AP62201 design is optimized for Electromagnetic Interference (EMI) reduction. The device has a proprietary gate driver scheme to resist switching node ringing without sacrificing MOSFET turn-on and turn-off times, which reduces high-frequency radiated EMI noise caused by MOSFET switching.

AP62201 is available in the space-saving SOT563 package.

FEATURES

- V_{IN} Range: 4.2V -18V
- Output Voltage range: 0.8V to 7V
- 2A Continuous Output Current
- 0.8V ± 1% Reference Voltage (T_A = +25°C) => AP62201
- 135µA Low Quiescent Current
- 740kHz Switching Frequency
- Proprietary Gate Driver Design for Best EMI Reduction
- Protection Circuitry

- Undervoltage Lockout (UVLO)
- Cycle-by-Cycle Valley Current Limit
- Thermal Shutdown
- Totally Lead-Free & Fully RoHS Compliant
- Halogen and Antimony Free.
 "Green" Device

APPLICATIONS

- Flat Screen TV Sets and Monitors
- Consumer Electronics
- Network Systems
- General Purpose Point of Load



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Rating	Unit			
VIN	Supply Pin Voltage	-0.3 to +20.0 (DC)	V			
VIIN	Supply Fill Voltage	-0.3 to 22.0 (400ms)	1 v			
V _{SW}	Switch Pin Voltage	-1.0 to VIN + 0.3 (DC)	V			
	Switch Fill Voltage	-2.5 to VIN + 2.0 (20ns)] v			
V_{BST}	Bootstrap Pin Voltage	V_{SW} - 0.3 to V_{SW} + 6.0	V			
V_{EN}	Enable/UVLO Pin Voltage -0.3 to +6.0		V			
V_{FB}	Feedback Pin Voltage	-0.3 to +6.0	V			
T _{ST}	Storage Temperature	-65 to +150	°C			
T_J	Junction Temperature	+150	°C			
T _L	Lead Temperature	+260	°C			
ESD Susceptibility						
HBM	Human Body Mode	2000	V			
CDM	Charge Device Model	500	V			

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Rating	Unit	
V_{IN}	Supply Voltage	4.2 to 18	V	
V _{OUT}	Output Voltage Range	0.8 to 7	V	
T _A	Operating Ambient Temperature	-40 to +85	°C	
Tυ	Operating Junction Temperature	-40 to +125	°C	

SETTING OUTPUT VOLTAGE:

Table 1 for AP62201 shows a list of recommended component selections for common output voltages.

Vouт	C1	C2, C3	R1	R2	L1	C6
1.2V	10μF	2 x 22µF	4.99ΚΩ	10ΚΩ	2.2µH	100nF
1.5V	10μF	2 x 22µF	8.66ΚΩ	10ΚΩ	2.2µH	100nF
1.8V	10μF	2 x 22µF	12.4ΚΩ	10ΚΩ	3.3µH	100nF
2.5V	10μF	2 x 22µF	21.5ΚΩ	10ΚΩ	3.3µH	100nF – 220nF
3.3V	10μF	2 x 22µF	31.6ΚΩ	10ΚΩ	3.3µH	100nF – 330nF
5.0V	10µF	2 x 22µF	52.3ΚΩ	10ΚΩ	4.7µH	100nF – 330nF

Table 1. Common Output Voltages



EVALUATION BOARD

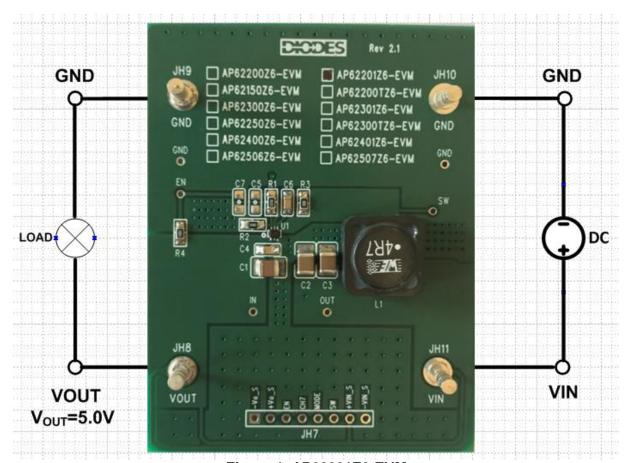


Figure 1. AP62201Z6-EVM

QUICK START GUIDE

The AP62201Z6-EVM has a simple layout and allows access to the appropriate signals through test points. To evaluate the performance of the AP62201Z6, follow the procedure below:

- 1. Connect a power supply to the input terminals VIN and GND. Set VIN to 12V.
- 2. Connect the positive terminal of the electronic load to Vout and negative terminal to GND.
- 3. EN has a positive voltage through a 100K pull-up to Vin. No supply input is required for EN.
- 4. The evaluation board should now power up with a 5.0V output voltage.



- 5. Check for the proper output voltage of 5.0V (±1%) at the output terminals Vouτ and GND. Measurement can also be done with a multimeter with the positive and negative leads between Vouτ and GND.
- 6. Set the load to 2A through the electronic load. Check for the stable operation of the SW signal on the oscilloscope. Measure the switching frequency.

MEASUREMENT/PERFORMANCE GUIDELINES:

- 1) When measuring the output voltage ripple, maintain the shortest possible ground lengths on the oscilloscope probe. Long ground leads can erroneously inject high-frequency noise into the measured ripple.
- 2) For efficiency measurements, connect an ammeter in series with the input supply to measure the input current. Connect an electronic load to the output for output current.

BOOTSTRAP CAPACITOR GUIDELINES:

To ensure proper operation, a ceramic capacitor must be connected between the BST and SW pins to supply the drive voltage for the high-side power MOSFET. A 100nF ceramic capacitor is sufficient for most applications. In the cases where output voltage is higher than 2.5V, a higher capacitance is recommended to help maintain stable voltage from BST to SW. Please refer to Table 1 for details.



EVALUATION BOARD SCHEMATIC

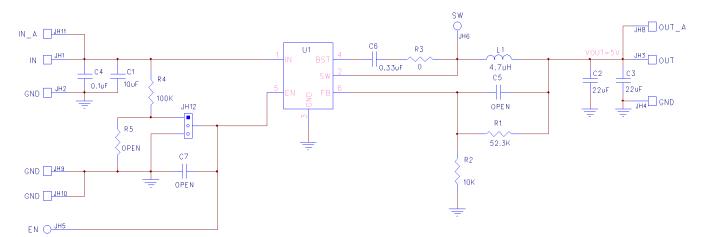


Figure 2. AP62201Z6-EVM Schematic

PCB TOP LAYOUT

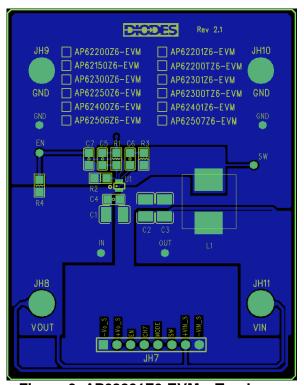


Figure 3. AP62201Z6-EVM – Top Layer



PCB BOTTOM LAYOUT

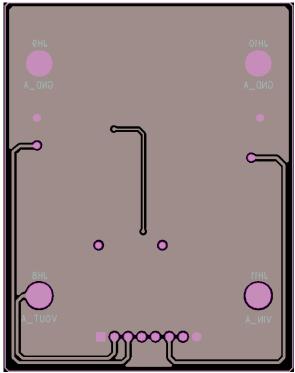


Figure 4. AP62201Z6-EVM - Bottom Layer

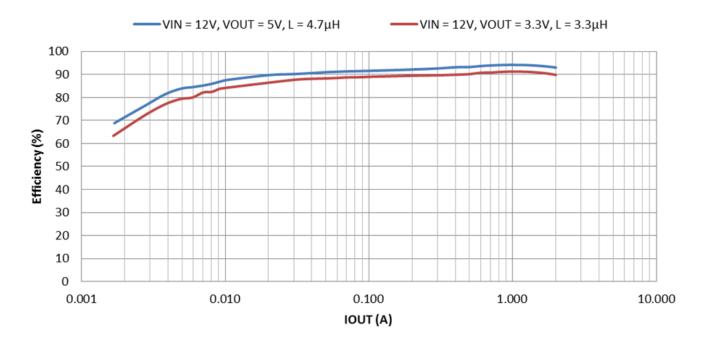


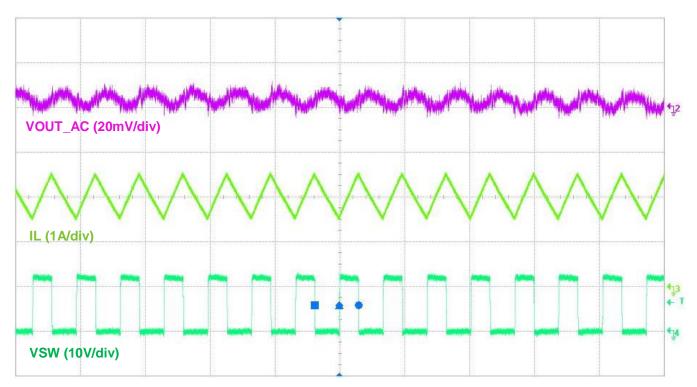
BILL OF MATERIALS for AP62201Z6-EVM for V_{OUT}=5V

Ref	Value	Description	Qty	Size	Vendor Name	Manufacturer PN
		Ceramic Capacitor,	_			
C1	10μF	25V, X7R, 10%	1	1210	KEMET	C1210C106K3RACTU
C2, C3	22µF	Ceramic Capacitor, 25V, X7R, 10%	2	1210	KEMET	C1210C226K3RAC780 0
C4	0.1µF	Ceramic Capacitor, 50V, X7R, 10%	1	0603	KEMET	C0603C104K5RACTU
C6	0.33µF	Ceramic Capacitor, 16V, X7R, 10%	1	0603	Samsung	CL10B334KO8NNNC
L1	4.7µH	DCR=19.5mΩ, Ir=6.2A	1	10.2X10.2 x4.5mm	Wurth Electronics	744779747
R1	52.3ΚΩ	SMD Resistor, 1%	1	0603	Panasonic	ERJ-3EKF5232V
R2	10ΚΩ	SMD Resistor, 1%	1	0603	Panasonic	ERJ-3EKF1002V
R3	0Ω	SMD Resistor, 1%	1	0603	Panasonic	ERJ-3GEY0R00V
R4	100ΚΩ	SMD Resistor, 1%	1	0603	Panasonic	ERJ-3EKF1003V
JH4, JH5, JH6,	4500	Terminal Turret Triple 0.094" L	4	Through-	Keystone	4500.0
JH7	1598	(Test Points) PCB Header, 40	4	Hole	Circuit	1598-2
JH8		POS Header, 40	1	1X3	3M	2340-6111TG
U1	AP62201	Sync Buck DC/DC converter	1	TSOT26	Diodes Incorporated	AP62201Z6-7



TYPICAL PERFORMANCE CHARACTERISTICS







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